Diode Semiconductor Device - Page 1 of 1



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	e Material:
Glass	
Overall L	Length:
Between	0.230 inches and 0.300 inches
Termina	I Length:
1.000 inc	ches
Overall [	Diameter:
Between	0.085 inches and 0.107 inches
End App	blication:
F/16 a-c	81775 fscm
Joint Ele	ectronic Device Engineering Council/jedec/case Outline Designation:
Do-7	
Mountin	g Method:
Terminal	
Features	s Provided:
Hermetic	ally sealed case
Semicor	nductor Material:
Silicon	
Voltage	Rating In Volts Per Characteristic:
20.0 rev	erse voltage, dc
Power R	ating Per Characteristic:
400.0 mi	lliwatts small-signal input power, common-collector preset
Maximu	m Operating Tempurature Per Measurement Point:
175.0 de	grees celsius ambient air
Termina	I Type And Quantity:
2 uninsul	lated wire lead
Shelf Lif	e:
N/a	
Unit Of M	Measure:
Demilita	rization:
No	
Fiig:	
A110a0	